

Bi-directional 5V Low Capacitance ESD Protector

Description

The PESDMC2XD5VB protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, low operating voltage. It gives designer the flexibility to protect one bi-directional line in applications where arrays are not practical.



Feature

- \rightarrow 40W peak pulse power per line ($t_P = 8/20\mu s$)
- DFN0603-2L package
- Replacement for MLV(0201)
- Bidirectional configurations
- Response time is typically < 1ns</p>
- Low clamping voltage
- RoHS compliant
- Transient protection for data lines to IEC61000-4-2(ESD) ±15KV(air), ±15KV(contact); IEC61000-4-4 (EFT) 40A (5/50ns)

Pin 1 Circuit Diagram

Applications

- Cellular phones
- Portable devices
- Digital cameras
- Power supplies



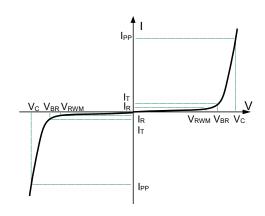
Marking (Top View)

Mechanical Characteristics

- Lead finish:100% matte Sn(Tin)
- Mounting position: Any
- ➤ Qualified max reflow temperature:260 °C
- Device meets MSL 1 requirements

Electronics Parameter

Symbol	Parameter		
V _{RWM}	Peak Reverse Working Voltage		
I _R	Reverse Leakage Current @ V _{RWM}		
V _{BR}	Breakdown Voltage @ I⊤		
lτ	Test Current		
I _{PP}	Maximum Reverse Peak Pulse Current		
Vc	Clamping Voltage @ I _{PP}		
P _{PP}	Peak Pulse Power		
CJ	Junction Capacitance		



Electrical characteristics per line@25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Peak Reverse Working Voltage	V_{RWM}				5.0	V
Breakdown Voltage	V_{BR}	I _t = 1mA	7.0		9.0	V
Reverse Leakage Current	I _R	V _{RWM} = 5V T=25℃			1.0	μΑ
Maximum Reverse Peak Pulse Current	I _{PP}			4.2		Α
Clamping Voltage	V_{CL}	I _{PP} =16A t _p =100ns		14.0		V
Clamping Voltage	Vc	I _{PP} =1A		10	12	V
Clamping Voltage	Vc	I _{PP} =3A		10	12	V
Clamping Voltage	Vc	I _{PP} =4A		10	12	V
Junction Capacitance	Cj	V _R =0V f = 1MHz		0.42	0.5	pF

Absolute maximum rating@25℃

Rating	Symbol	Value	Units
Peak Pulse Power (t _p =8/20µs)	P _{pp}	40	W
Operating Temperature	TJ	-55 to 150	$^{\circ}\!$
Storage Temperature	T _{STG}	-55 to 150	${}^{\mathbb{C}}$

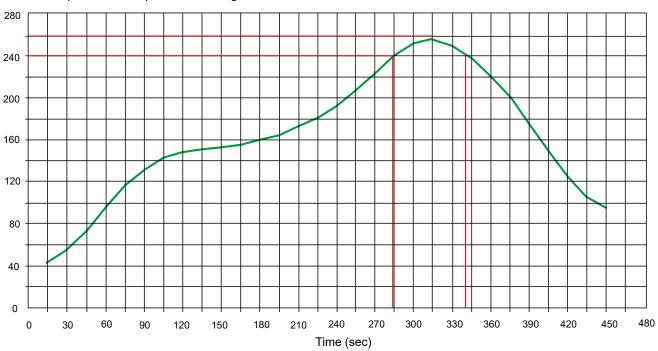
Typical Characteristics f=8µs 100 100 <u>d</u> IPP - Peak Pulse Current - % of 80 80 % Of Rated Power 60 60 =20µs 40 40 20 20 0 0 0 5 15 25 30 0 25 50 75 100 125 150 T_L – Lead Temperature - ${}^\circ\!\mathbb{C}$ t - Time -µs Fig 1.Pulse Waveform Fig 2.Power Derating Curve 20 0.515 f=1MHz 15 C-Junction capacitance (pf) C-Junction capacitance (pf) 0.485 10 TLP current(A) 5 0 -5 -10 -15 0.475 -20 -15 -10 10 15 6 TLP voltage(V) V_R-Reverse voltage (V) Fig 3.TLP Measurement Fig 4. Capacitance vs. Reveres voltage 1000 10.4 Pulse waveform: tp=8/20us 10.2 Vc-Clamping Voltage (V) 100 Peak Pulse Power (W) 10.0 9.6 10 9.2 8.8 1000 2 3 100 10 Pulse Duration(us) IPP-Peak pulse current (A)

Fig 6. Non-Repetitive Peak Pulse Power vs. Pulse time

Fig 5. Clamping voltage vs. Peak pulse current

Solder Reflow Recommendation

Peak Temp=257°C, Ramp Rate=0.802deg. °C/sec

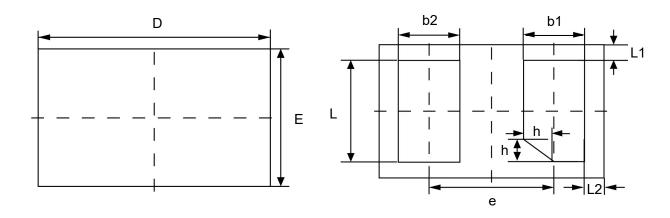


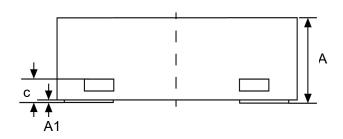
PCB Design

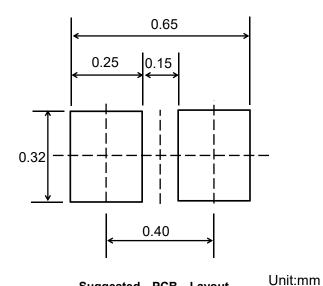
For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

- Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- Do not make false economies and save copper for the ground connection.
- Place via holes to ground as close as possible to the anode of the TVS diode.
- Use as many via holes as possible for the ground connection.
- > Keep the length of via holes in mind! The longer the more inductance they will have.

Product dimension (DFN0603-2L)







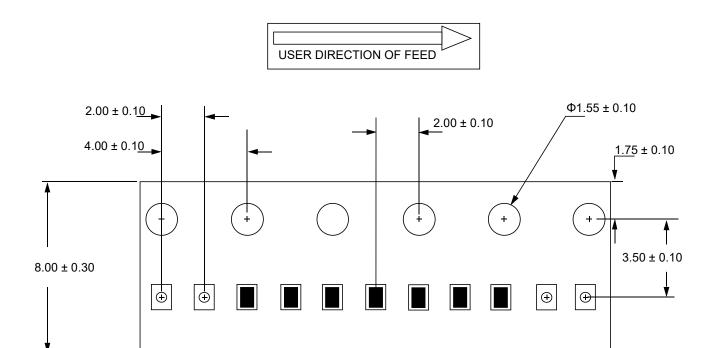
Suggested	PCB	Layout
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Dim	Millimeters				
	MIN	Тур.	MAX		
Α	0.28	0.30	0.32		
A1	0	0.02	0.05		
b1	0.13	0.18	0.23		
b2	0.14	0.19	0.24		
С	0.05	0.10	0.15		
D	0.55	0.60	0.65		
е	0.35BSC				
L1	0.025BSC				
L2	0.035BSC				
E	0.25	0.30	0.35		
L	0.20	0.25	0.30		
h	0	0.05	0.10		

Ordering information

Device	Package	Reel	Shipping
PESDMC2XD5VB	DFN0603-2L (Pb-Free)	7"	12000 / Tape & Reel

Load with information



Unit: mm

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